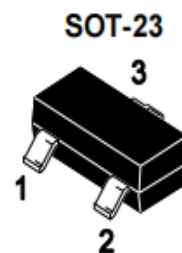
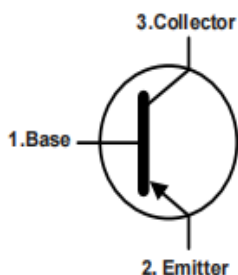


## PNP Transistor

### Features

- For Switching and AF Amplifier Applications.

### Equivalent Circuit



1.Base 2.Emitter 3.Collector

**Marking Code : 593**

### Absolute Maximum Ratings

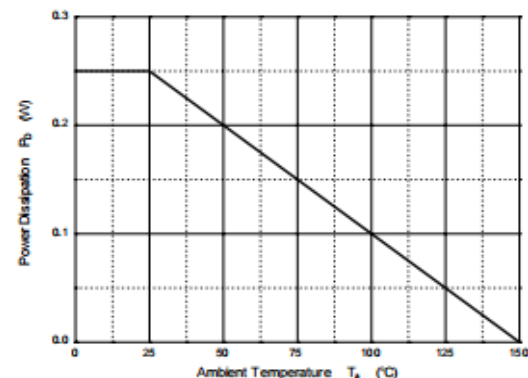
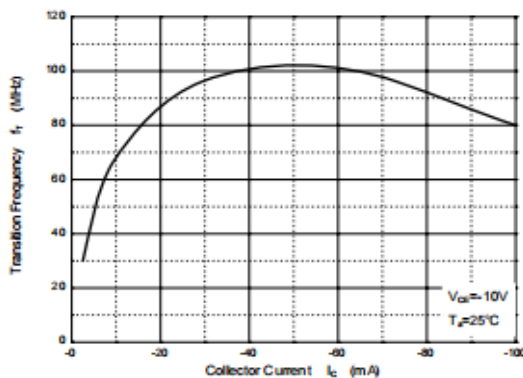
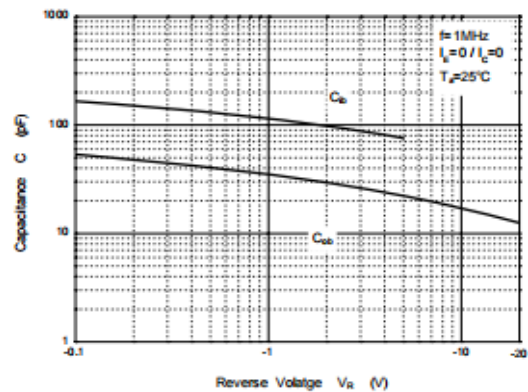
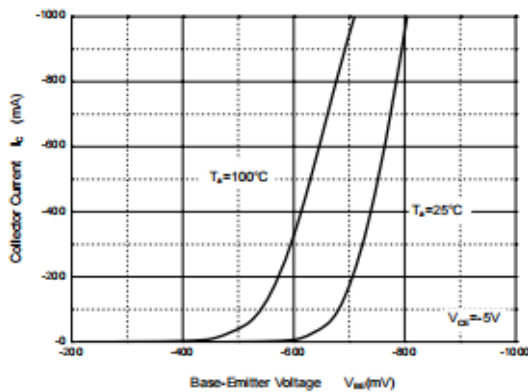
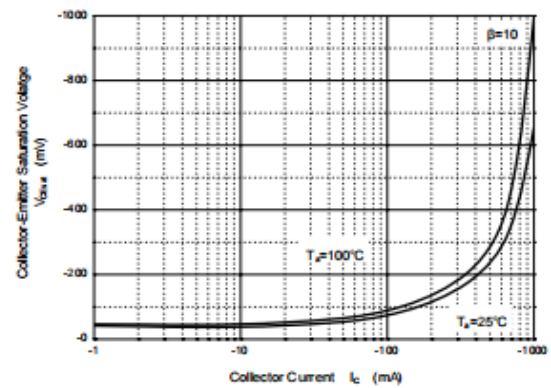
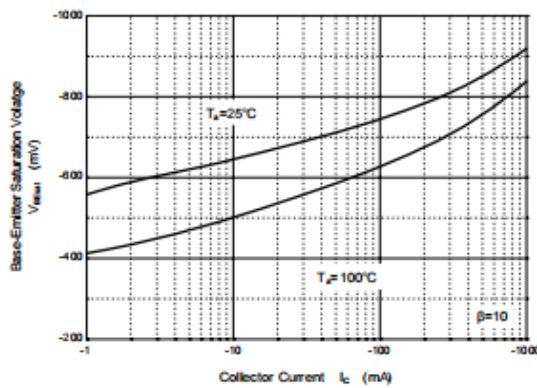
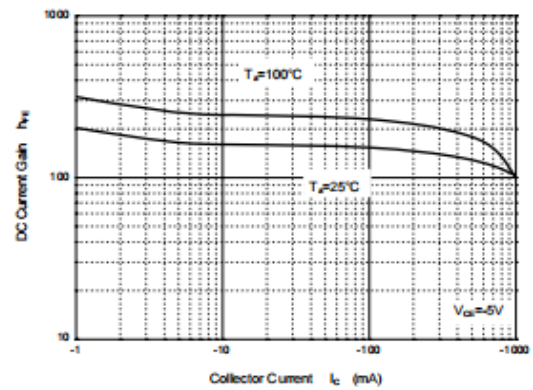
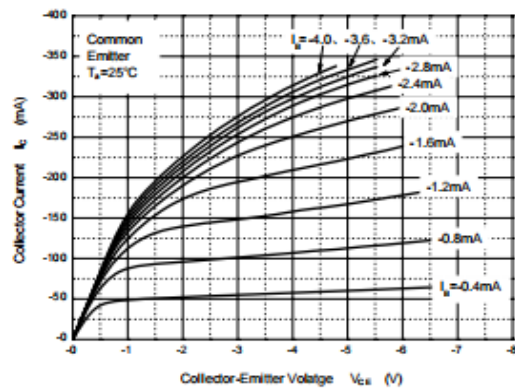
Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Collector Base Voltage	$-V_{CBO}$	120	V
Collector Emitter Voltage	$-V_{CEO}$	100	V
Emitter Base Voltage	$-V_{EBO}$	5	V
Collector Current	$-I_C$	1	A
Maximum Power Dissipation	$P_D$	250	mW
Junction Temperature	$T_J$	150	°C
Storage Temperature Range	$T_{STG}$	-55 to +150	°C

**Electrical Characteristics (T<sub>A</sub>=25°C)**

Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at V <sub>CE</sub> = -5 V, I <sub>C</sub> = -1 mA at V <sub>CE</sub> = -5 V, I <sub>C</sub> = -250 mA at V <sub>CE</sub> = -5 V, I <sub>C</sub> = -0.5 A at V <sub>CE</sub> = -5 V, I <sub>C</sub> = -1 A	H <sub>FE</sub>	100 100 100 50	-- -- 300 --	--
Collector Base Cutoff Current at V <sub>CB</sub> = -100V	-I <sub>CBO</sub>	--	0.1	μA
Collector Emitter Cutoff Current at V <sub>CES</sub> = -100V	-I <sub>CES</sub>	--	0.1	μA
Emitter Base Cutoff Current at V <sub>EB</sub> = -4 V	-I <sub>EBO</sub>	--	0.1	μA
Collector Base Breakdown Voltage at I <sub>C</sub> = -100 μA	-V <sub>(BR)CBO</sub>	120	--	V
Collector Emitter Breakdown Voltage at I <sub>C</sub> = -1 mA	-V <sub>(BR)CEO</sub>	100	--	V
Emitter Base Breakdown Voltage at I <sub>E</sub> = -100 μA	-V <sub>(BR)EBO</sub>	5	--	V
Collector Emitter Saturation Voltage at I <sub>C</sub> = -250 mA, I <sub>B</sub> = -25 mA at I <sub>C</sub> = -500 mA, I <sub>B</sub> = -50 mA	-V <sub>CE(sat)</sub>	-- --	0.2 0.3	V
Base Emitter Saturation Voltage at I <sub>C</sub> = -500 mA, I <sub>B</sub> = -50 mA	-V <sub>BE(sat)</sub>	--	1.1	V
Base Emitter On Voltage at V <sub>CE</sub> = -5 V, I <sub>C</sub> = -1mA	-V <sub>BE(on)</sub>	--	1	V
Transition Frequency at V <sub>CE</sub> = -10 V, I <sub>C</sub> = -50 mA, f = 100 MHz	F <sub>T</sub>	150	--	MHz
Collector Output Capacitance at V <sub>CB</sub> = -10 V, f = 1 MHz	C <sub>ob</sub>	--	5	pF

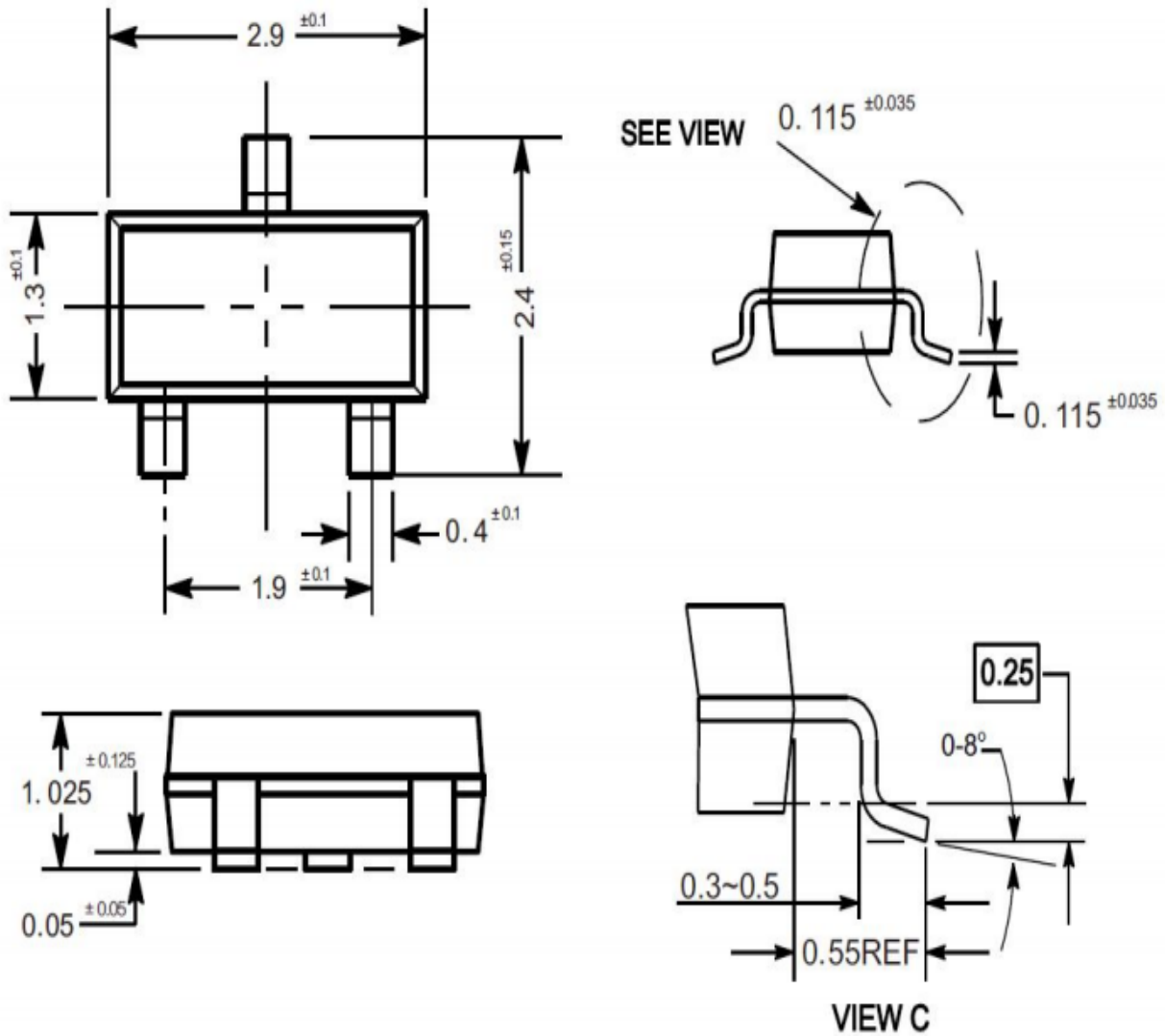
## Typical Characteristic Curves



## Package Outline

SOT-23

Dimensions in mm

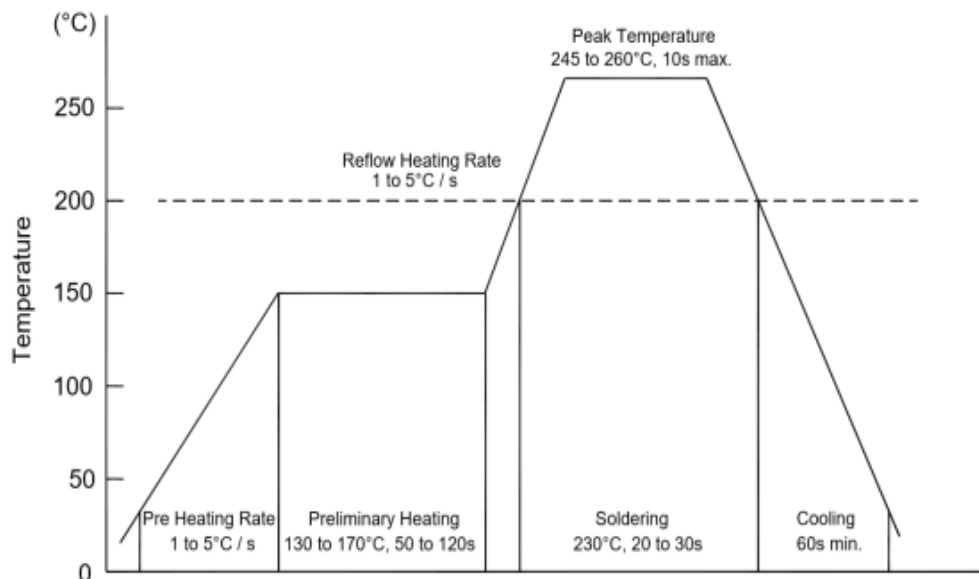


## Ordering Information

Device	Package	Shipping
FMMT593	SOT-23	3,000PCS/Reel&7inches

## Conditions of Soldering and Storage

### ◆ Recommended condition of reflow soldering



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters:

- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

### ◆ Conditions of hand soldering

- Temperature: 370 °C
- Time: 3s max.
- Times: one time

### ◆ Storage conditions

- **Temperature**  
5 to 40 °C
- **Humidity**  
30 to 80% RH
- **Recommended period**  
One year after manufacturing